Dual DPDT Ultra-Low R_{ON} Switch

The NLAS3699 is a dual independent ultra-low R_{ON} DPDT analog switch. This device is designed for low operating voltage, high current switching of speaker output for cell phone applications. It can switch a balanced stereo output. The NLAS3699 can handle a balanced microphone/speaker/ring—tone generator in a monophone mode. The device contains a break—make feature.

Features

- Single Supply Operation
 1.65 to 4.7 V V_{CC}
 Function Directly from LiON Battery
- Maximum Breakdown Voltage: 5.0 V
- Tiny 3 x 3 mm QFN Pb–Free Package Meet JEDEC MO–220 Specifications
- Low Static Power

Typical Applications

- Cell Phone Speaker/Microphone Switching
- Ringtone-Chip/Amplifier Switching
- Four Unbalanced (Single-Ended) Switches
- Stereo Balanced (Push-Pull) Switching

Important Information

• ESD Protection:

HBM (Human Body Model) > 4000 V MM (Machine Model) > 400 V

- Continuous Current Rating Through each Switch ±300 mA
- Conforms to: JEDEC MO-220, Issue H, Variation VEED-6
- Pin for Pin Compatible with STG3699



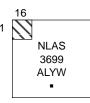
ON Semiconductor®

http://onsemi.com

MARKING DIAGRAMS



QFN-16 CASE 485AE



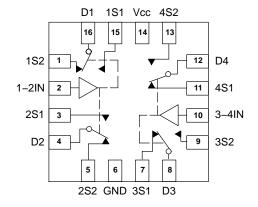
XXXX = Specific Device Code

A = Assembly Location

L = Wafer Lot Y = Year

W = Work Week

= Pb-Free Package



ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 9 of this data sheet.

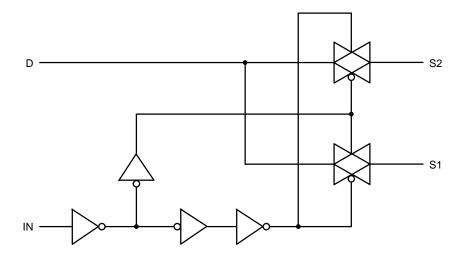


Figure 1. Input Equivalent Circuit

PIN DESCRIPTION

QFN PIN #	Symbol	Name and Function
1, 3, 5, 7, 9, 11, 13, 15	1S1 to 4S1, 1S2 to 4S2	Independent Channels
2, 10	1-2IN, 3-4IN	Controls
4, 8, 12, 16	D1 to D4	Common Channels
6	GND	Ground (V)
14	V _{CC}	Positive Supply Voltage

TRUTH TABLE

IN	S 1	S2
Н	ON	OFF(*)
L	OFF(*)	ON

^{*}High impedance.

MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
V _{CC}	Positive DC Supply Voltage	-0.5 to +5.0	V
V _{IS}	Analog Input Voltage (V _{NO} , V _{NC} , or V _{COM})	$-0.5 \le V_{IS} \le V_{CC} + 0.5$	V
V _{IN}	Digital Select Input Voltage	$-0.5 \le V_{\parallel} \le +5.0$	V
I _{anl1}	Continuous DC Current from COM to NC/NO	±300	mA
I _{anl-pk 1}	Peak Current from COM to NC/NO, 10 duty cycle (Note 1)	±500	mA
I _{clmp}	Continuous DC Current into COM/NO/NC with respect to V _{CC} or GND	±100	mA

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

1. Defined as 10% ON, 90% off duty cycle.

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter		Min	Max	Unit
V _{CC}	DC Supply Voltage		1.65	4.7	V
V _{IN}	Digital Select Input Voltage	GND	V _{CC}	V	
V _{IS}	Analog Input Voltage (NC, NO, COM)		GND	V _{CC}	V
T _A	Operating Temperature Range		- 55	+ 125	°C
t _r , t _f	Input Rise or Fall Time, SELECT $$V_{\rm CC}$$	= 1.6 V - 2.7 V = 3.0 V - 4.7 V		20 10	ns/V

DC CHARACTERISTICS - Digital Section (Voltages Referenced to GND)

				Guaranteed Limit			
Symbol	Parameter	Condition	V _{CC} ±10%	−55°C to 25°C	<85°C	<125°C	Unit
V _{IH}	Minimum High-Level Input Voltage, Select Inputs		1.8 2.5 4.7	1.2 1.7 2.8	1.2 1.7 2.8	1.2 1.7 2.8	V
V _{IL}	Maximum Low-Level Input Voltage, Select Inputs		1.8 2.5 4.7	0.4 0.5 1.0	0.4 0.5 1.0	0.4 0.5 1.0	V
I _{IN}	Maximum Input Leakage Current, Select Inputs	V _{IN} = 5.0 V or GND	4.7	± 0.1	± 1.0	± 1.0	μΑ
I _{OFF}	Power Off Leakage Current	V _{IN} = 5.0 V or GND	0	± 0.5	±2.0	±2.0	μΑ
Icc	Maximum Quiescent Supply Current (Note 2)	Select and $V_{IS} = V_{CC}$ or GND	1.65 to 4.7	± 1.0	± 2.0	± 2.5	μΑ

DC ELECTRICAL CHARACTERISTICS - Analog Section

				Guaranteed Maximum Limit												
				−55°C	-55°C to 25°C		-55°C to 25°C		–55°C to 25°C		-55°C to 25°C <85°C		5°C	<12	5°C	
Symbol	Parameter	Condition	V _{CC} ±10%	Min	Max	Min	Max	Min	Max	Unit						
R _{ON}	NC/NO On–Resistance (Note 2)	$\begin{split} &V_{IN} \leq V_{IL} \text{ or } V_{IN} \geq V_{IH} \\ &V_{IS} = GND \text{ to } V_{CC} \\ &I_{IN}I \leq 100 \text{ mA} \end{split}$	2.5 3.0 4.7		0.6 0.5 0.5		0.6 0.5 0.5		0.7 0.6 0.5	Ω						
R _{FLAT}	NC/NO On–Resistance Flatness (Notes 2, 4)	I _{COM} = 100 mA V _{IS} = 0 to V _{CC}	2.5 3.0 4.7		0.15 0.15 0.15		0.15 0.15 0.15		0.15 0.15 0.15	Ω						
ΔR_{ON}	On–Resistance Match Between Channels (Notes 2 and 3)	$V_{IS} = 1.3 \text{ V};$ $I_{COM} = 100 \text{ mA}$ $V_{IS} = 1.5 \text{ V};$ $I_{COM} = 100 \text{ mA}$ $V_{IS} = 2.8 \text{ V};$ $I_{COM} = 100 \text{ mA}$	2.5 3.0 4.7		0.06 0.05 0.05		0.06 0.05 0.05		0.06 0.05 0.05	Ω						
I _{NC(OFF)} I _{NO(OFF)}	NC or NO Off Leakage Current (Note 2)	$\begin{aligned} &V_{IN} = V_{IL} \text{ or } V_{IH} \\ &V_{NO} \text{ or } V_{NC} = 0.8 \text{ V} \\ &V_{COM} = 3.7 \text{ V} \end{aligned}$	4.7	-5.0	5.0	-10	10	-100	100	nA						
I _{COM(ON)}	COM ON Leakage Current (Note 2)	$\begin{split} &V_{IN} = V_{IL} \text{ or } V_{IH} \\ &V_{NO} \ 0.8 \text{ V or } 3.7 \text{ V with} \\ &V_{NC} \text{ floating or} \\ &V_{NC} \ 0.8 \text{ V or } 3.7 \text{ V with} \\ &V_{NO} \text{ floating} \\ &V_{COM} = 0.8 \text{ V or } 3.7 \text{ V} \end{split}$	4.7	-10	10	-100	100	-1000	1000	nA						

Guaranteed by design. Resistance measurements do not include test circuit or package resistance.
 ΔR_{ON} = R_{ON(MAX)} – R_{ON(MIN)} between NC1 and NC2 or between NO1 and NO2.
 Flatness is defined as the difference between the maximum and minimum value of on–resistance as measured over the specified analog signal ranges.

AC ELECTRICAL CHARACTERISTICS (Input $t_r = t_f = 3.0 \text{ ns}$)

				Guaranteed Maximum Limit			Guaranteed I					
			V _{CC}	V _{IS}	-5	5°C to 2	25°C	<8	5°C	<12	25°C	
Symbol	Parameter	Test Conditions	(V)	(V)	Min	Тур*	Max	Min	Max	Min	Max	Unit
t _{ON}	Turn-On Time	$R_L = 50 \Omega$, $C_L = 35 pF$ (Figures 3 and 4)	2.3 – 4.7	1.5			50		60		60	ns
t _{OFF}	Turn-Off Time	$R_L = 50 \Omega$, $C_L = 35 pF$ (Figures 3 and 4)	2.3 – 4.7	1.5			30		40		40	ns
t _{BBM}	Minimum Break-Before- Make Time	$V_{IS} = 3.0$ $R_L = 300 \ \Omega, \ C_L = 35 \ pF$ (Figure 2)	3.0	1.5	2	15						ns

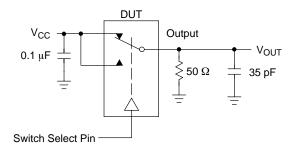
		Typical @ 25, V _{CC} = 5.0 V	
C _{IN}	Control Pin Input Capacitance	2.5	pF
C _{SN}	SN Port Capacitance	72	pF
C _D	D Port Capacitance When Switch is Enabled	230	pF

^{*}Typical Characteristics are at 25°C.

ADDITIONAL APPLICATION CHARACTERISTICS (Voltages Referenced to GND Unless Noted)

			V _{CC}	25°C	
Symbol	Parameter	Condition	(V)	Typical	Unit
BW	Maximum On–Channel –3dB Bandwidth or Minimum Frequency Response (Figure 12)	V _{IN} centered between V _{CC} and GND (Figure 5)	1.65 – 4.7	20	MHz
V _{ONL}	Maximum Feed-through On Loss	V_{IN} = 0 dBm @ 100 kHz to 50 MHz V_{IN} centered between V_{CC} and GND (Figure 5)	1.65 – 4.7	-0.06	dB
V _{ISO}	Off-Channel Isolation (Figure 13)	f = 100 kHz; V_{IS} = 1 V RMS; C_L = 5 nF V_{IN} centered between V_{CC} and GND(Figure 5)	1.65 – 4.7	-62	dB
Q	Charge Injection Select Input to Common I/O (Figure 8)	$V_{IN} = V_{CC \text{ to}} \text{ GND, } R_{IS} = 0 \Omega, C_L = 1 \text{ nF}$ $Q = C_L - \Delta V_{OUT} \text{ (Figure 6)}$	1.65 – 4.7	50	pC
THD	Total Harmonic Distortion THD + Noise (Figure 7)	F_{IS} = 20 Hz to 20 kHz, R_L = R_{gen} = 600 Ω , C_L = 50 pF V_{IS} = 2 V RMS	4.3	0.01	%
VCT	Channel-to-Channel Crosstalk	f = 100 kHz; V_{IS} = 1 V RMS, C_L = 5 pF, R_L = 50 Ω V_{IN} centered between V_{CC} and GND (Figure 5)	1.65 – 4.7	-62	dB

^{5.} Off-Channel Isolation = 20log10 (Vcom/Vno), Vcom = output, Vno = input to off switch.



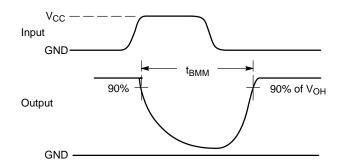
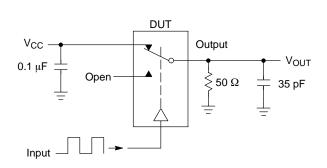


Figure 2. t_{BBM} (Time Break-Before-Make)



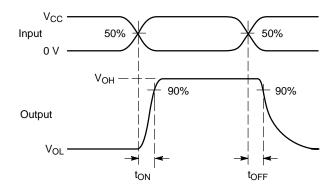
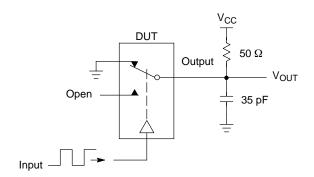


Figure 3. t_{ON}/t_{OFF}



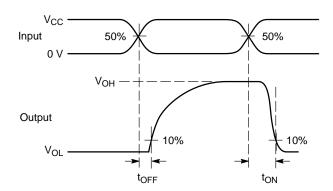
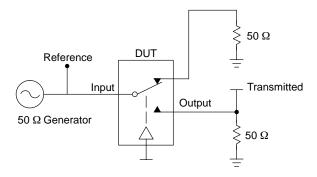


Figure 4. t_{ON}/t_{OFF}



Channel switch control/s test socket is normalized. Off isolation is measured across an off channel. On loss is the bandwidth of an On switch. V_{ISO} , Bandwidth and V_{ONL} are independent of the input signal direction.

$$V_{ISO}$$
 = Off Channel Isolation = 20 Log $\left(\frac{V_{OUT}}{V_{IN}}\right)$ for V_{IN} at 100 kHz

$$V_{ONL}$$
 = On Channel Loss = 20 Log $\left(\frac{V_{OUT}}{V_{IN}}\right)$ for V_{IN} at 100 kHz to 50 MHz

Bandwidth (BW) = the frequency 3 dB below V_{ONL}

 V_{CT} = Use V_{ISO} setup and test to all other switch analog input/outputs terminated with 50 Ω

Figure 5. Off Channel Isolation/On Channel Loss (BW)/Crosstalk (On Channel to Off Channel)/V_{ONL}

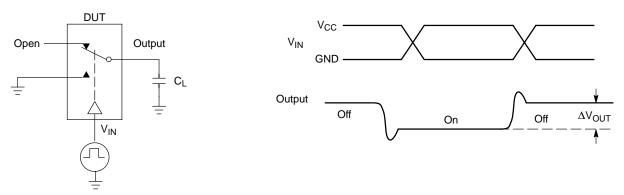


Figure 6. Charge Injection: (Q)

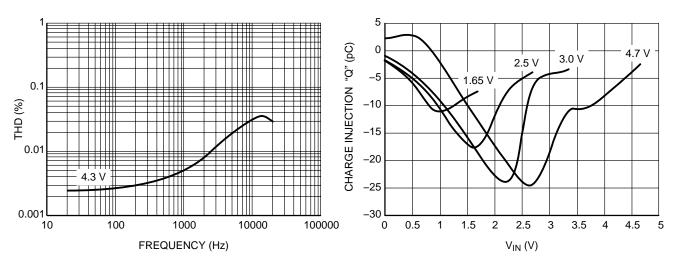


Figure 7. Total Harmonic Distortion Plus Noise Versus Frequency

Figure 8. Charge Injection versus Vis

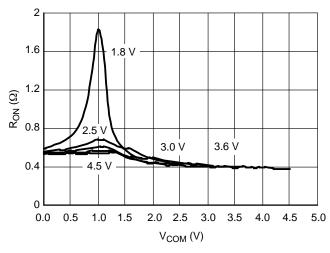


Figure 9. On-Resistance vs. COM Voltage

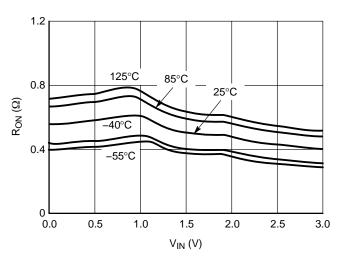


Figure 10. R_{ON} vs. V_{IN} vs. Temperature @ V_{CC} = 3.0 V

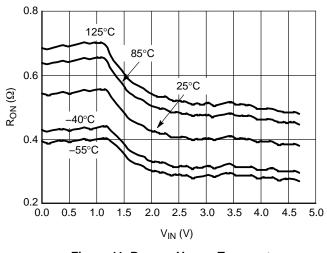


Figure 11. R_{ON} vs. V_{IN} vs. Temperature @ V_{CC} = 4.7 V

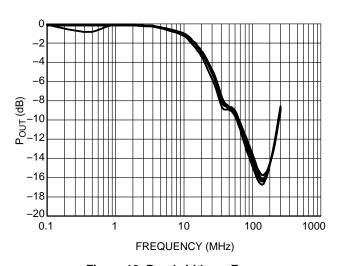


Figure 12. Bandwidth vs. Frequency
@ V_{CC} = 1.65 V to 4.7 V

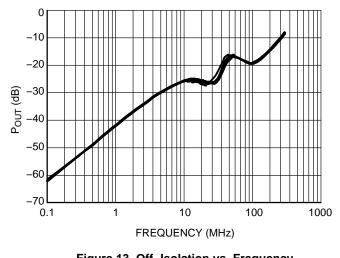


Figure 13. Off-Isolation vs. Frequency $@V_{CC} = 1.65 \text{ V}$ to 4.7 V

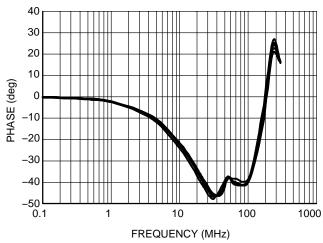


Figure 14. Phase Angle vs. Frequency @ V_{CC} = 1.65 V to 4.7 V

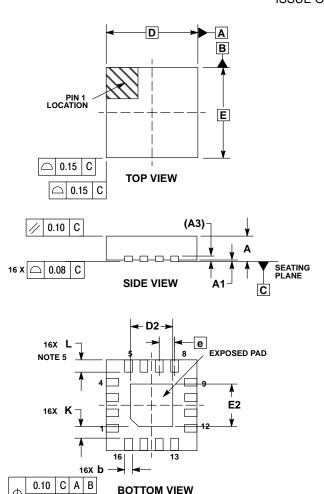
DEVICE ORDERING INFORMATION

		Devi	ce Nomenc	lature				
Device Order Number	Circuit Indicator	Technology	Device Function	Package Suffix	Tape & Reel Suffix	Package Type	Tape & Reel Size [†]	
NLAS3699MN1R2G	NL	AS	3699	MN1	R2	QFN (Pb-Free)	2500 Unit / Reel	

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

PACKAGE DIMENSIONS

QFN-16 (3 x 3 x 0.85 mm) CASE 485AE-01 **ISSUE O**



- NOTES:
 1. DIMENSIONING AND TOLERANCING PER
- ASME Y14.5M, 1994.
 CONTROLLING DIMENSION: MILLIMETERS.
 DIMENSION b APPLIES TO PLATED
 TERMINAL AND IS MEASURED BETWEEN 0.25 AND 0.30 MM FROM TERMINAL
- COPLANARITY APPLIES TO THE EXPOSED PAD AS WELL AS THE TERMINALS.

 OUTLINE MEETS JEDEC DIMENSIONS PER MO–220, VARIATION VEED–6.

	MILLIMETERS						
DIM	MIN NOM MAX						
Α	0.800	0.900	1.000				
A1	0.000	0.025	0.050				
A3		0.200 RE	F				
b	0.180	0.300					
D		3.00 BS	С				
D2	1.250	1.40	1.550				
Е		3.00 BS	С				
E2	1.250	1.40	1.550				
е		0.500 BS	C				
K	0.200	0.200					
L	0.300	0.400	0.500				

ON Semiconductor and was are registered trademarks of Semiconductor Components Industries, LLC (SCILLC). SCILLC reserves the right to make changes without further notice to any products herein. SCILLC makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does SCILLC assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. "Typical" parameters which may be provided in SCILLC data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. SCILLC does not convey any license under its partnif rights nor the rights of others. SCILLC products are not designed, intended, or authorized for use as components in systems intended for surgical implant into the body, or other applications intended to support or sustain life, or for any other application in which the failure of the SCILLC product could create a situation where personal injury or death may occur. Should Buyer purchase or use SCILLC products for any such unintended or unauthorized application, Buyer shall indemnify and hold SCILLC and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that SCILLC was negligent regarding the design or manufacture of the part. SCILLC is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

PUBLICATION ORDERING INFORMATION

С 0.05

NOTE 3

LITERATURE FULFILLMENT:

Literature Distribution Center for ON Semiconductor P.O. Box 61312, Phoenix, Arizona 85082-1312 USA Phone: 480-829-7710 or 800-344-3860 Toll Free USA/Canada Fax: 480-829-7709 or 800-344-3867 Toll Free USA/Canada Email: orderlit@onsemi.com

N. American Technical Support: 800-282-9855 Toll Free

Japan: ON Semiconductor, Japan Customer Focus Center 2-9-1 Kamimeguro, Meguro-ku, Tokyo, Japan 153-0051 Phone: 81-3-5773-3850

ON Semiconductor Website: http://onsemi.com

Order Literature: http://www.onsemi.com/litorder

For additional information, please contact your local Sales Representative.